



DMTH10H010LPS

100V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C	
100V	8.6mΩ @ V _{GS} = 10V	98.4A	

Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize $R_{DS(ON)}$, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

Applications

- Motor Control
- DC-DC Converters
- Power Management

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

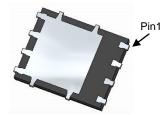
Mechanical Data

- Case: PowerDI[®] 5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.097 grams (Approximate)

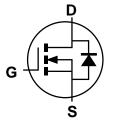
PowerDI5060-8



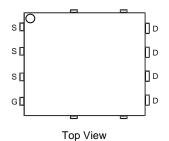
Top View



Bottom View



Internal Schematic



Pin Configuration

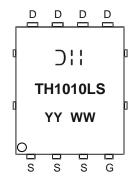
Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH10H010LPS-13	PowerDI5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



| | = Manufacturer's Marking TH1010LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17= 2017) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V_{DSS}	100	V
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current (/ 40V)	Steady State	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I _D	10.8 7.6	А
Continuous Drain Current (V _{GS} = 10V)	Steady State	$T_C = +25$ °C $T_C = +100$ °C	I _D	98.4 69.6	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	250	Α		
Maximum Continuous Body Diode Forward Current			Is	95	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			I _{SM}	250	Α
Avalanche Current, L=0.3mH			I _{AS}	15	Α
Avalanche Energy, L=0.3mH			E _{AS}	33.7	mJ

Thermal Characteristics

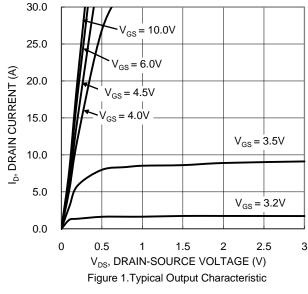
Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P_{D}	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	99	°C/W
Total Power Dissipation	T _C = +25°C	P _D	125	W
Thermal Resistance, Junction to Case	R _{0JC}	1.2	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +175	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	1	1	٧	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	l	l	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	1	1	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V _{GS(TH)}	1.4	1.9	3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
		I	6.9	8.6		$V_{GS} = 10V, I_D = 13A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	1	7.5	12	mΩ	$V_{GS} = 6V, I_D = 13A$	
		-	10	20		$V_{GS} = 4.5V, I_D = 5A$	
Diode Forward Voltage	V_{SD}	I	0.8	1.3	٧	$V_{GS} = 0V, I_{S} = 13A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	1	2592	_		$V_{DS} = 50V$, $V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	1	792	1	pF		
Reverse Transfer Capacitance	C _{rss}	1	45	_			
Gate Resistance	R_g	I	2	1	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Q_g	1	53.7	1		\/ F0\/ I- 12A	
Gate-Source Charge	Q_{gs}	I	10.6	1	nC	$V_{DD} = 50V, I_D = 13A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q_{gd}	l	8.2	1		VGS = 10V	
Turn-On Delay Time	t _{D(ON)}		11.6				
Turn-On Rise Time	t _R	I	14.1	_	no	$V_{DD} = 50V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(OFF)}	I	42.9	1	ns	$I_D = 13A$, $R_g = 6\Omega$	
Turn-Off Fall Time	t _F	1	22	_			
Reverse Recovery Time	t _{RR}	_	49.8	_	ns	I 12	
Reverse Recovery Charge	Q _{RR}	_	85.1	_	nC	I _F = 13A, di/dt = 100A/μs	

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to product testing.





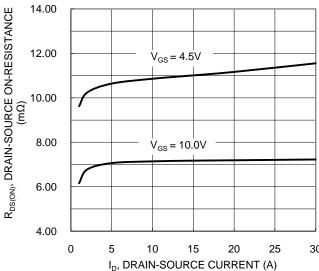


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

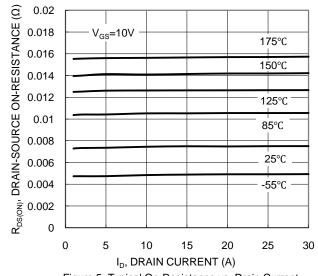
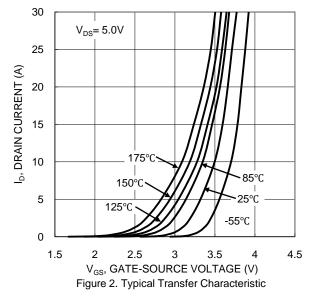
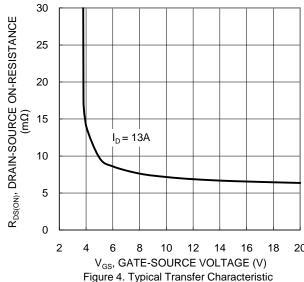


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





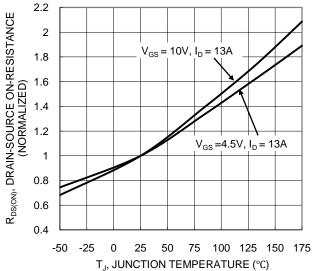


Figure 6. On-Resistance Variation with Temperature





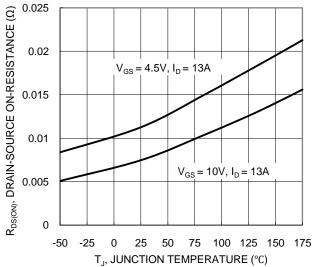


Figure 7. On-Resistance Variation with Temperature

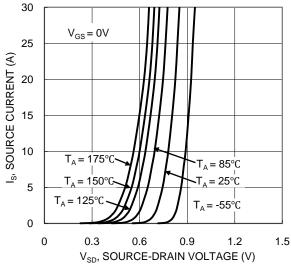


Figure 9. Diode Forward Voltage vs. Current

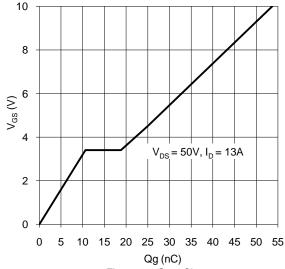


Figure 11. Gate Charge

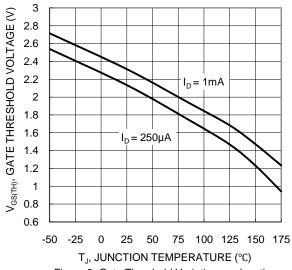
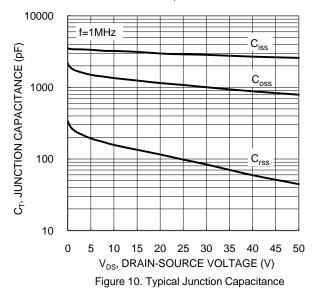
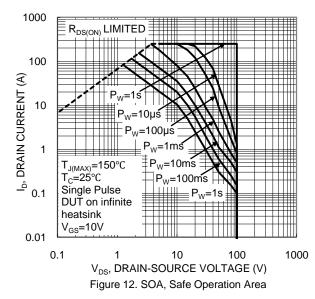


Figure 8. Gate Threshold Variation vs. Junction Temperature







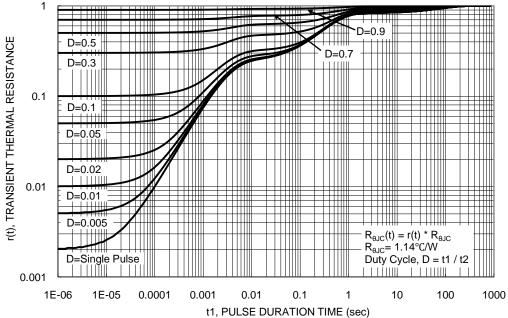


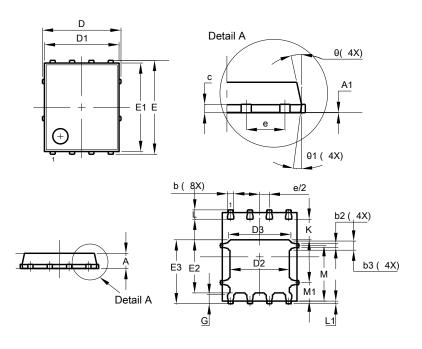
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

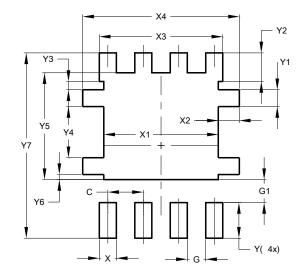


PowerDI5060-8						
Dim	Min	Тур				
Α	0.90	1.10	1.00			
A1	0.00	0.05	_			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D	,	5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90 4.30 4.10					
Е	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	3.99 4.39 4.19				
e G	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
θ	10º	12º	11º			
θ1	6°	80	7º			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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